

N-Channel JFET Monolithic Dual



SST5911 / SST5912

FEATURES

- High Gain $g_{fs} > 6 \text{ mS}$
- Low Leakage $I_G < 1 \text{ pA typical}$
- Low Noise
- Surface Mount Package

APPLICATIONS

- Differential Wideband Amplifier
- VHF/UHF Amplifiers
- Test and Measurement

DESCRIPTION

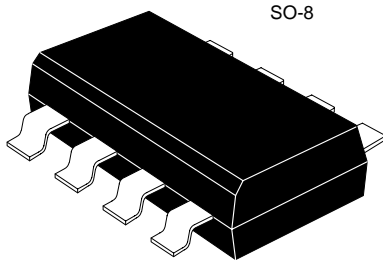
The SST5912 is a High Speed N-Channel Monolithic JFET pair encapsulated in a surface mount plastic SO-8 package. The device is designed for high gain (typically $> 6000 \mu\text{mhos}$), low leakage ($< 1 \text{ pA}$ typically) and low noise. The SST5912 is an excellent choice for differential wideband amplifiers, VHF/UHF amplifiers and test and measurement.

ORDERING INFORMATION

Part	Package	Temperature Range
SST5912	Plastic SO-8 Package	-55°C to +150°C

NOTE: For Sorted Chips in Carriers, See 2N5911 Series

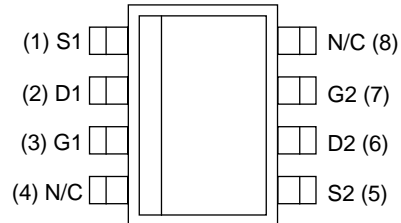
PIN CONFIGURATION



SO-8

CJ1

TOP VIEW



PRODUCT MARKING

SST5912	SST5912
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ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter/Test Condition	Symbol	Limit	Unit
Gate-Drain Voltage	V_{GD}	-25	V
Gate-Source Voltage	V_{GS}	-25	V
Forward Gate Current	I_G	50	mA
Power Dissipation (per side)	P_D	300	mW
(total)		500	mW
Power Derating (per side)		2.4	mW/°C
(total)		4	mW/°C
Operating Junction Temperature	T_J	-55 to 150	°C
Storage Temperature	T_{stg}	-65 to 150	°C
Lead Temperature (1/16" from case for 10 seconds)	T_L	300	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

SYMBOL	CHARACTERISTICS	TYP ¹	SST5912		UNIT	TEST CONDITIONS
			MIN	MAX		
STATIC						
$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	-35	-25		V	$I_G = -1\mu\text{A}, V_{DS} = 0\text{V}$
$V_{GS(OFF)}$	Gate-Source Cut off Voltage	-3.5	-1	-5		$V_{DS} = 10\text{V}, I_D = 1\text{nA}$
I_{DSS}	Saturation Drain Current ²	15	7	40	mA	$V_{DS} = 10\text{V}, V_{GS} = 0\text{V}$
I_{GSS}	Gate Reverse Current	-1		-100	pA	$V_{GS} = -15\text{V}, V_{DS} = 0\text{V}$
		-0.2			nA	$T_A = 125^\circ\text{C}$
I_G	Gate Operating Current	-1		-100	pA	$V_{DG} = 10\text{V}, I_D = 5\text{mA}$
		-0.2			nA	$T_A = 125^\circ\text{C}$
V_{GS}	Gate-Source Voltage	-1.5	-0.3	-4	V	$V_{DG} = 10\text{V}, I_D = 5\text{mA}$
$V_{GS(F)}$	Gate-Source Forward Voltage	0.7				$I_G = 1\text{mA}, V_{DS} = 0\text{V}$
DYNAMIC						
g_{fs}	Common-Source Forward Transconductance	6	5	10	mS	$V_{DG} = 10\text{V}, I_D = 5\text{mA}$ $f = 1\text{kHz}$
g_{os}	Common-Source Output Conductance	20		100	μS	
g_{fs}	Common-Source Forward Transconductance	6	5	10	mS	$V_{DG} = 10\text{V}, I_D = 5\text{mA}$ $f = 100\text{MHz}$
g_{os}	Common-Source Output Conductance	30		150	μS	
C_{iss}	Common-Source Input Capacitance	3.5		5	pF	$V_{DG} = 10\text{V}, I_D = 5\text{mA}$ $f = 1\text{MHz}$
C_{rss}	Common-Source Reverse Transfer Capacitance	1		1.2		
\bar{e}_n	Equivalent Input Noise Voltage	4		20	nV/ $\sqrt{\text{Hz}}$	$V_{DG} = 10\text{V}, I_D = 5\text{mA}, f = 10\text{kHz}$
NF	Noise Figure	0.1		1	dB	$V_{DG} = 10\text{V}, I_D = 5\text{mA}, f = 10\text{kHz}, R_G = 100\Omega$

ELECTRICAL CHARACTERISTICS (continued) ($T_A = 25^\circ\text{C}$ unless otherwise noted)

SYMBOL	CHARACTERISTICS	SST5911		SST5912		UNITS	TEST CONDITIONS	
		MIN	MAX	MIN	MAX			
$ I_{G1} - I_{G2} $	Differential Gate Current		20		20	nA	$V_{DG} = 10\text{V}, I_D = 5\text{mA}, T_A = 125^\circ\text{C}$	
$\frac{I_{DSS1}}{I_{DSS2}}$	Saturation Drain Current Ratio	0.95	1	0.95	1		$V_{DS} = 10\text{V}, V_{GS} = 0$ (Pulsewidth 300 μs , duty cycle $\leq 3\%$)	
$ V_{GS1} - V_{GS2} $	Differential Gate-Source Voltage		10		15	mV	$V_{DG} = 10\text{V}, I_D = 5\text{mA}$	
$\frac{\Delta V_{GS1} - V_{GS2} }{\Delta T}$	Gate Source Voltage Differential Drift (Measured at end points, T_A and T_B)		20		40	$\mu\text{V}/^\circ\text{C}$		$T_A = 25^\circ\text{C}$ $T_B = 125^\circ\text{C}$
			20		40			$T_A = -55^\circ\text{C}$ $T_B = 25^\circ\text{C}$
$\frac{g_{fs1}}{g_{fs2}}$	Transconductance Ratio	0.95	1	0.95	1		$f = 1\text{kHz}$	

- NOTES:** 1. For design aid only, not subject to production testing.
2. Pulse test; PW = 300 μs , duty cycle $\leq 3\%$.

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Datasheets for electronics components.